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DATASHEET

HA-2850

470MHz, Low Power, High Slew Rate Operational Amplifier

FN2844
Rev 5.00
May 2003

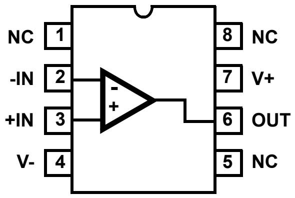
The HA-2850 is a wideband, high slew rate, operational amplifier featuring superior speed and bandwidth characteristics. Bipolar construction, coupled with dielectric isolation, delivers outstanding performance in circuits with a closed loop gain of 10 or greater.

A 340V/µs slew rate and a 470MHz gain bandwidth product ensure high performance in video and wideband amplifier designs. Differential gain and phase are a low 0.04% and 0.04 degrees respectively, making the HA-2850 ideal for video applications. A full ±10V output swing, high open loop gain, and outstanding AC parameters, make the HA-2850 an excellent choice for high speed Data Acquisition Systems.

For military grade product, refer to the HA-2850/883 data sheet.

Pinout

HA-2850 (SOIC)
TOP VIEW



Features

- Low Supply Current 7.5mA
- High Slew Rate 340V/µs
- Open Loop Gain. 25kV/V
- Wide Gain-Bandwidth ($A_V \geq 10$). 470MHz
- Full Power Bandwidth 5.4MHz
- Low Offset Voltage. 0.6mV
- Input Noise Voltage . . . . $11nV/\sqrt{Hz}$
- Differential Gain/Phase . . . . 0.04%/0.04 Degrees
- Lower Power Enhanced Replacement for AD840 and EL2040

Applications

- Pulse and Video Amplifiers
- Wideband Amplifiers
- High Speed Sample-Hold Circuits
- Fast, Precise D/A Converters

Part Number Information

PART NUMBER (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HA9P2850-5 (H28505)	0 to 75	8 Ld SOIC	M8.15

Absolute Maximum Ratings

Voltage Between V+ and V- Terminals	35V
Differential Input Voltage	6V

Operating Conditions

Temperature Range	
HA-2850-5	0°C to 75°C
Recommended Supply Voltage Range	±6V To ±15V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
8 Ld SOIC Package	157
Maximum Junction Temperature (Die)	175°C
Maximum Junction Temperature (Plastic Package, Note 2)	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

1. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.
2. Maximum power dissipation, including output load, must be designed to maintain the maximum junction temperature below 150°C for plastic packages.

Electrical Specifications

V_{SUPPLY} = ±15V, R_L = 1kΩ, $C_L \leq$ 10pF, Unless Otherwise Specified

			HA-2850-5			
PARAMETER	**TEST CONDITIONS**	**TEMP. (°C)**	**MIN**	**TYP**	**MAX**	**UNITS**
INPUT CHARACTERISTICS						
Offset Voltage (Note 9)		25	-	0.6	2	mV
		Full	-	2	6	mV
Average Offset Voltage Drift		Full	-	20	-	μV/°C
Bias Current (Note 9)		25	-	5	14.5	μA
		Full	-	8	20	μA
Offset Current		25	-	1	4	μA
		Full	-	-	8	μA
Input Resistance		25	-	10	-	kΩ
Input Capacitance		25	-	1	-	pF
Common Mode Range		Full	±10	-	-	V
Input Noise Voltage (Note 9)	f = 1kHz, R_{SOURCE} = 0Ω	25	-	11	-	$nV/\sqrt{Hz}$
Input Noise Current (Note 9)	f = 1kHz, R_{SOURCE} = 10kΩ	25	-	6	-	$pA/\sqrt{Hz}$
TRANSFER CHARACTERISTICS						
Large Signal Voltage Gain	Note 4	25	20	25	-	kV/V
		Full	15	20	-	kV/V
Common-Mode Rejection Ratio (Note 9)	V_{CM} = ±10V	Full	75	80	-	dB
Minimum Stable Gain		25	10	-	-	V/V
Gain Bandwidth Product (Note 9)	V_O = 90mV, A_V = 100	25	-	470	-	MHz
OUTPUT CHARACTERISTICS						
Output Voltage Swing (Note 9)	Note 4	Full	±10	±11	-	V
Output Current (Note 9)	Note 4	Full	±10	±20	-	mA
Output Resistance		25	-	30	-	Ω
Full Power Bandwidth (Note 5)	Note 4	25	4.8	5.4	-	MHz
Differential Gain	A_V = +10, Note 3	25	-	0.04	-	%
Differential Phase	A_V = +10, Note 3	25	-	0.04	-	Degrees
Harmonic Distortion (Note 9)	A_V = +10, V_O = $2V_{P-P}$, f = 1MHz	25	-	-74	-	dBc

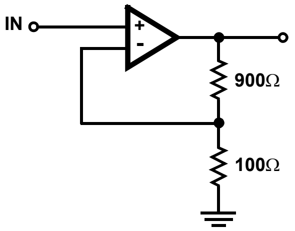
Electrical Specifications $V_{SUPPLY} = \pm15V$, $R_L = 1k\Omega$, $C_L \le 10pF$, Unless Otherwise Specified **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP. (°C)	HA-2850-5			UNITS
			MIN	TYP	MAX	
TRANSIENT RESPONSE (Note 6)						
Rise Time		25	-	5	-	ns
Overshoot		25	-	25	-	%
Slew Rate (Notes 8, 9)	Note 4	25	300	340	-	V/µs
Settling Time	10V Step to 0.1%	25	-	200	-	ns
POWER REQUIREMENTS						
Supply Current (Note 9)		Full	-	7.5	8.0	mA
Power Supply Rejection Ratio (Note 9)	Note 7	Full	75	90	-	dB

NOTES:

3. Differential gain and phase are measured with a VM700A video tester, using a NTC-7 composite VITS.
4. $R_L = 1k\Omega$, $V_O = \pm10V$, 0V to ±10V for slew rate.
5. Full Power Bandwidth guaranteed based on slew rate measurement using: $FPBW = \frac{\text{Slew Rate}}{2\pi V_{PEAK}}$; $V_{PEAK} = 10V$.
6. Refer to Test Circuit section of data sheet.
7. $V_{SUPPLY} = \pm10V$ to $\pm20V$.
8. This parameter is not tested. The limits are guaranteed based on lab characterization, and reflect lot-to-lot variation.
9. See "Typical Performance Curves" for more information.

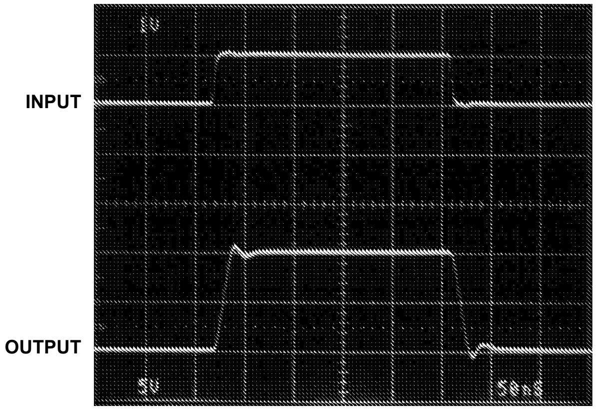
Test Circuits and Waveforms



NOTES:

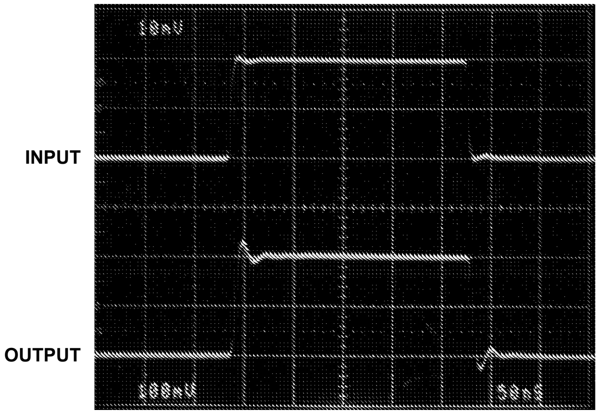
10. $V_S = \pm15V$.
11. $A_V = +10$.
12. $C_L < 10pF$.

TEST CIRCUIT



Input = 1V/Div.
Output = 5V/Div.
50ns/Div.

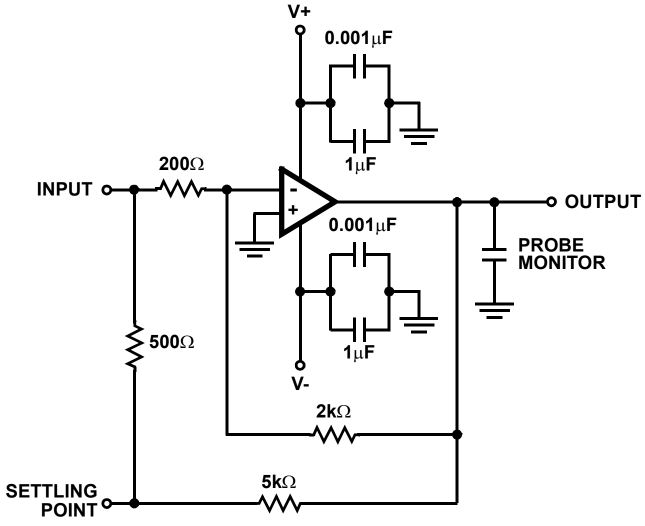
LARGE SIGNAL RESPONSE



Input = 10mV/Div.
Output = 100mV/Div.
50ns/Div.

SMALL SIGNAL RESPONSE

Test Circuits and Waveforms (Continued)



SETTLING TIME TEST CIRCUIT

NOTES:

13. A_V = -10.
14. Load Capacitance should be less than 10pF.
15. It is recommended that resistors be carbon composition and that feedback and summing network ratios be matched to 0.1%.
16. SETTLING POINT (Summing Node) capacitance should be less than 10pF. For optimum settling time results, it is recommended that the test circuit be constructed directly onto the device pins. A Tektronix 568 Sampling Oscilloscope with S-3A sampling heads is recommended as a settle point monitor.

Typical Performance Curves $T_A = 25^oC$, $V_{SUPPLY} = \pm 15V$, $R_L = 1k\Omega$, $C_L < 10pF$, Unless Otherwise Specified

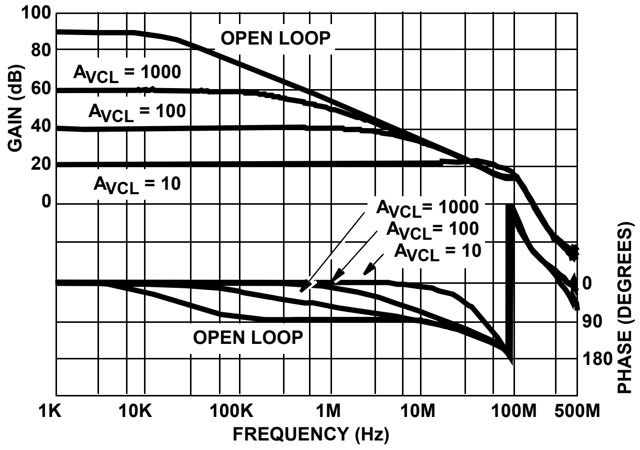


FIGURE 1. FREQUENCY RESPONSE FOR VARIOUS GAINS

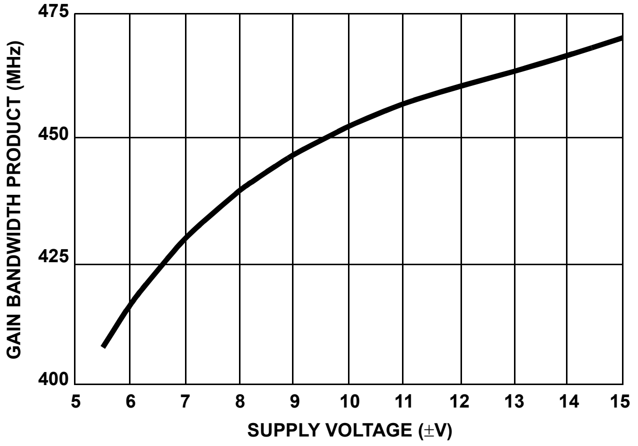


FIGURE 2. GAIN BANDWIDTH PRODUCT vs SUPPLY VOLTAGE

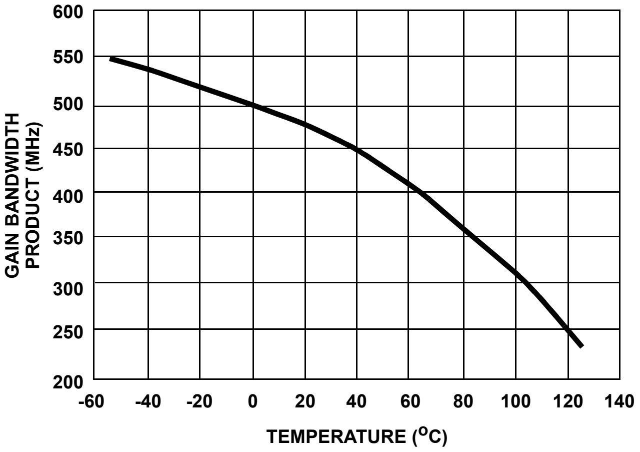


FIGURE 3. GAIN BANDWIDTH PRODUCT vs TEMPERATURE

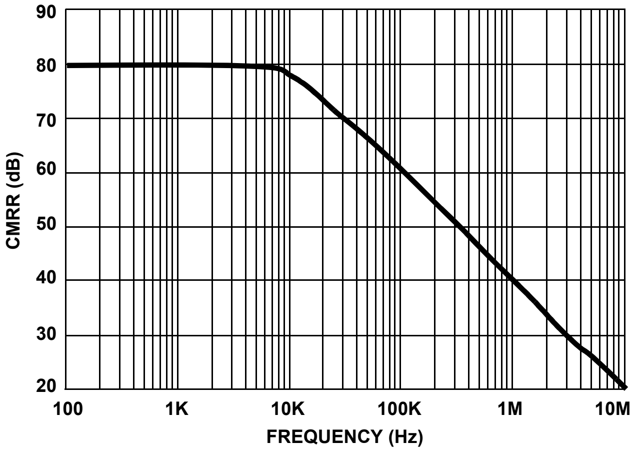


FIGURE 4. CMRR vs FREQUENCY

Typical Performance Curves $T_A = 25^oC$, $V_{SUPPLY} = \pm15V$, $R_L = 1k\Omega$, $C_L < 10pF$, Unless Otherwise Specified **(Continued)**

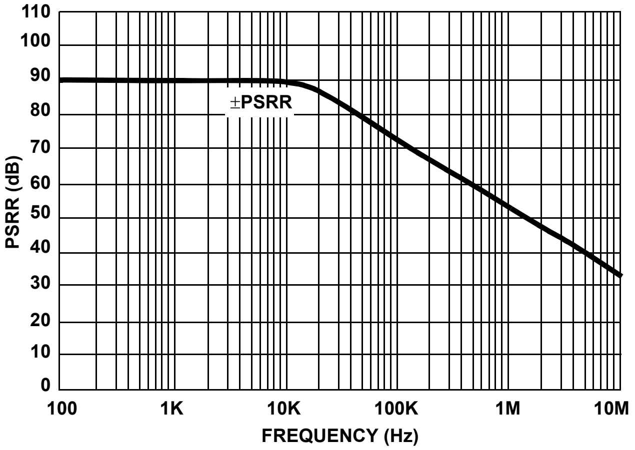


FIGURE 5. PSRR vs FREQUENCY

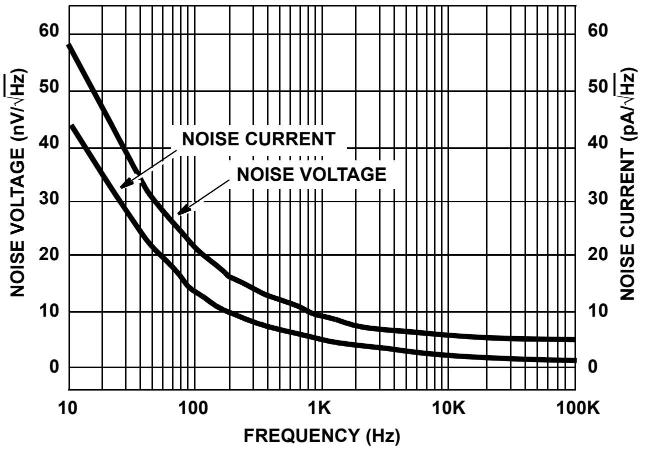


FIGURE 6. INPUT NOISE vs FREQUENCY

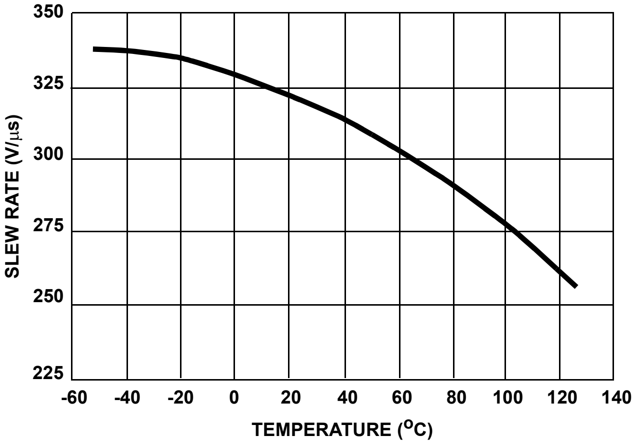


FIGURE 7. SLEW RATE vs TEMPERATURE

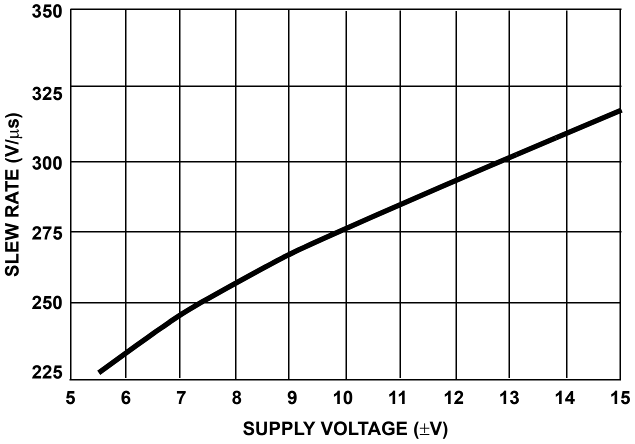


FIGURE 8. SLEW RATE vs SUPPLY VOLTAGE

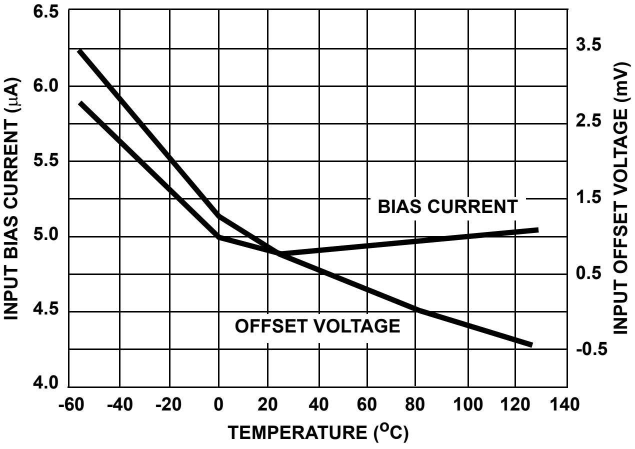


FIGURE 9. INPUT OFFSET VOLTAGE AND INPUT BIAS CURRENT vs TEMPERATURE

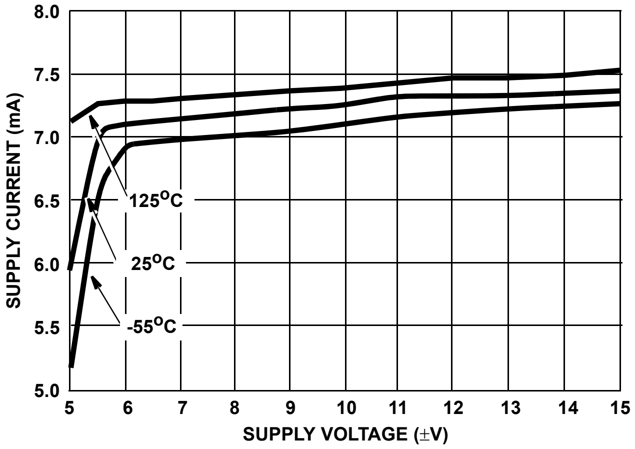


FIGURE 10. SUPPLY CURRENT vs SUPPLY VOLTAGE

Typical Performance Curves $T_A = 25^oC$, $V_{SUPPLY} = \pm15V$, $R_L = 1k\Omega$, $C_L < 10pF$, Unless Otherwise Specified **(Continued)**

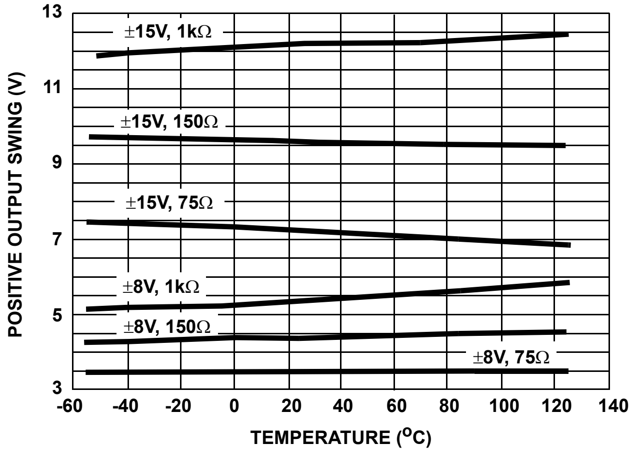


FIGURE 11. POSITIVE OUTPUT SWING vs TEMPERATURE

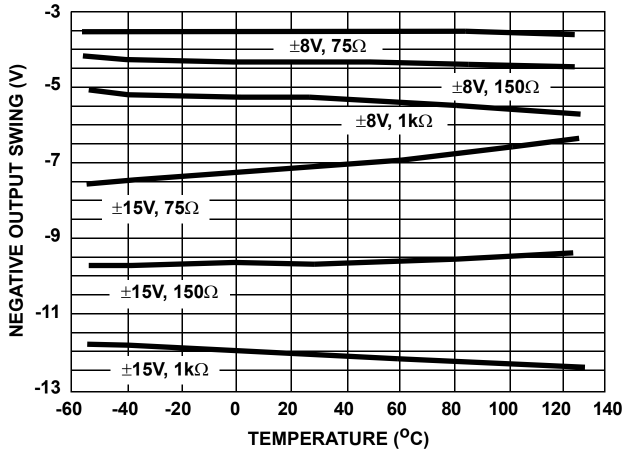


FIGURE 12. NEGATIVE OUTPUT SWING vs TEMPERATURE

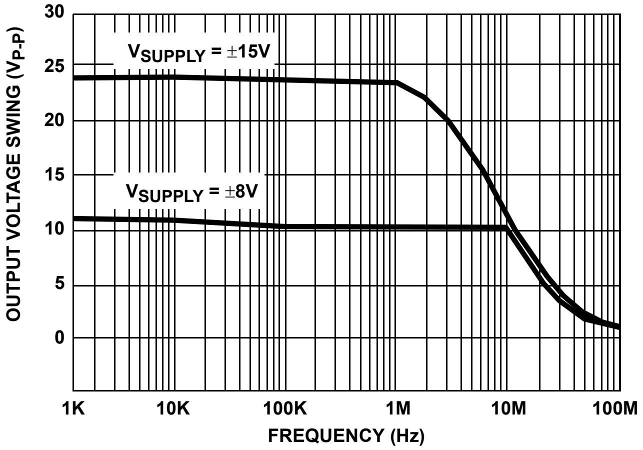


FIGURE 13. MAXIMUM UNDISTORTED OUTPUT SWING vs FREQUENCY

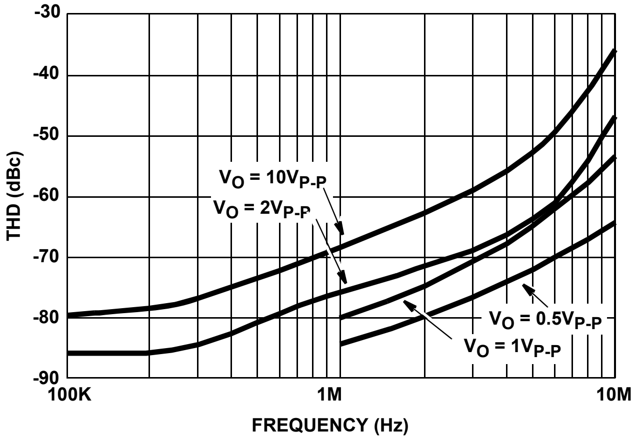


FIGURE 14. TOTAL HARMONIC DISTORTION vs FREQUENCY

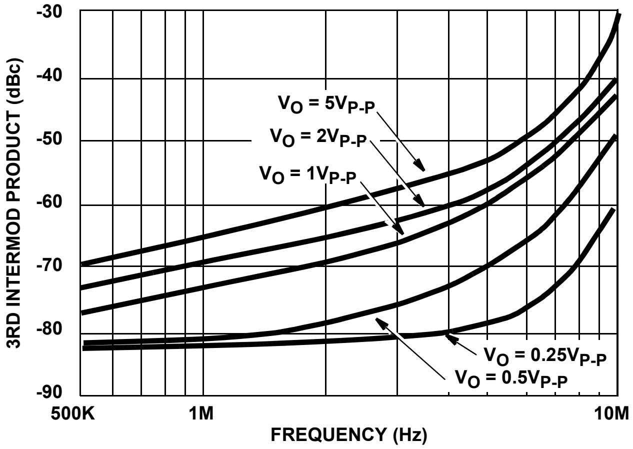


FIGURE 15. INTERMODULATION DISTORTION vs FREQUENCY (TWO TONE)

Die Characteristics

DIE DIMENSIONS:

65 mils x 52 mils x 19 mils
1650µm x 1310µm x 483µm

METALLIZATION:

Type: Aluminum, 1% Copper
Thickness: 16kÅ ±2kÅ

SUBSTRATE POTENTIAL

V-

PASSIVATION:

Type: Nitride over Silox
Silox Thickness: 12kÅ ±2kÅ
Nitride Thickness: 3.5kÅ ±1kÅ

TRANSISTOR COUNT:

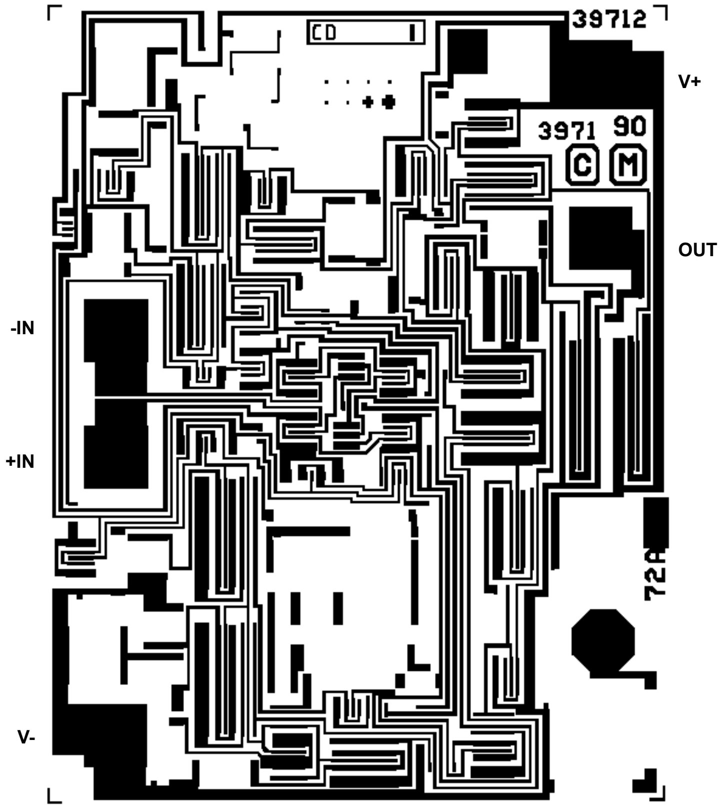
34

PROCESS:

High Frequency Bipolar Dielectric Isolation

Metallization Mask Layout

HA-2850



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